

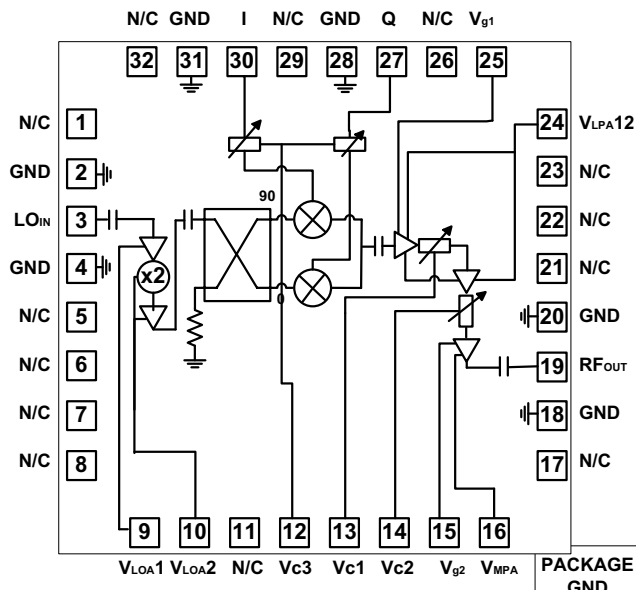


Features

- RF Frequency: 17.7GHz to 19.7GHz
- LO Frequency: 6.85GHz to 11.85GHz
- IF Frequency: DC to 4GHz
- Conversion Gain (Max): 21dB
- Conversion Gain (Min): -5dB
- NF (Max. Gain): 9dB
- NF (Min. Gain): 18dB
- OIP3 (Max. Gain): +28dBm
- OIP3 (Min. Gain): +10dBm
- Image Rejection: $\geq 15\text{dBc}$

Applications

- Point-to-Point
- VSAT



Functional Block Diagram

Product Description

RFMD's RFUV1702 is a 17.7GHz to 19.7GHz GaAs pHEMT upconverter, incorporating an integrated frequency multiplier (x2), LO buffer amplifier, a balanced single sideband (image rejection) mixer followed by variable gain amplifier, and DC decoupling capacitors. The combination of high performance parts and low-cost packaging makes the RFUV1702 a cost-effective solution, ideally suited to both current and next generation point-to-point and VSAT applications. RFUV1702 is packaged in a 5mm x 5mm QFN to simplify both system level board design and volume assembly.

Ordering Information

RFUV1702S2	2-Piece Sample Bag
RFUV1702SB	5-Piece Bag
RFUV1702SQ	25-Piece Bag
RFUV1702SR	100 Pieces on 7" reel
RFUV1702TR7	750 Pieces on 7" reel
RFUV1702PCBA-410	Evaluation Board

Absolute Maximum Ratings

Parameter	Rating	Unit
LPA Drain Voltage V_D	6	V
LOA Drain Voltage	6	V
IF Input Power	15	dBm
LO Input Power	15	dBm
T_{OPER}	-55 to +85	°C
T_{STOR}	-65 to +150	°C
ESD Human Body Model	Class 1A	



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Nominal Operating Parameters

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
RF Frequency	17.7		19.7	GHz	
LO Frequency	6.85		11.85	GHz	
IF Frequency	DC		4.0	GHz	
LO input Drive		0		dBm	
Conversion Gain (Max.)		21		dB	
Conversion Gain (Min.)		-5		dB	
NF (Max. Gain)		9		dB	
NF (-5dB Gain)		18		dB	
OIP3 (Max. Gain)		28		dBm	
OIP3 (-5dB Gain)		10		dBm	
Image Rejection		15		dBc	
LO Leakage at RF-Port (Max. Gain)		-5		dBm	With IQ bias
LO Return Loss		10		dB	
RF Return Loss		10		dB	
V_{VA}	-4		0	V	
V_{MPA}		4.5		V	
V_{LPA12}		3.5		V	
V_{LOA1}, V_{LOA2}		4		V	
I_{LOA1}, I_{LOA2}		206		mA	
I_{LPA12}^*		120		mA	Adjust $V_{G1} \approx -0.4V$ to achieve $I_{LPA12} = 120mA$
I_{MPA}^*		120		mA	Adjust $V_{G2} \approx -0.4V$ to achieve $I_{MPA} = 120mA$

*Note: These currents can be adjusted to optimize performance for varying application requirements.

Typical Electrical Performance

Measurements performed on connectorized evaluation board as shown on P.8 with I and Q (IF) ports connected to an external 90° Hybrid, LO Power = 0dBm and IF = 2.5GHz, -10dBm, $V_{LPA12} = 3.5V$, $I_{V_{LPA12}} = 120mA^*$, $V_{MPA} = 4.5V$, $I_{V_{MPA}} = 120mA^{**}$,
 $V_{LOA1} = V_{LOA2} = 4V$ and $V_{C1} = V_{C2} = V_{C3} = -4V$, unless otherwise stated.

*Adjust V_{G1} around -0.45V to get $I_{V_{LPA12}} = 120mA$

**Adjust V_{G2} around -0.45V to get $I_{V_{MPA}} = 120mA$

USB Conversion Gain, Image Rejection, OIP3, and LO Leakage

Max Conversion Gain versus RF Frequency (USB)

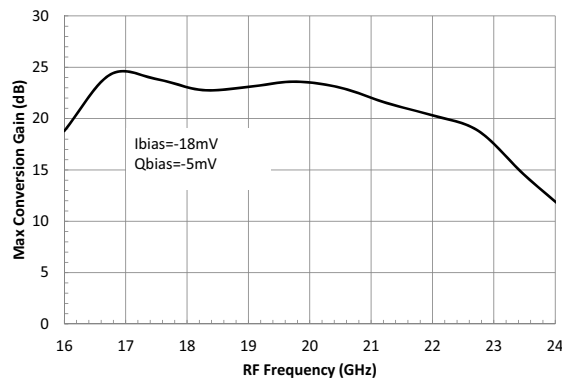
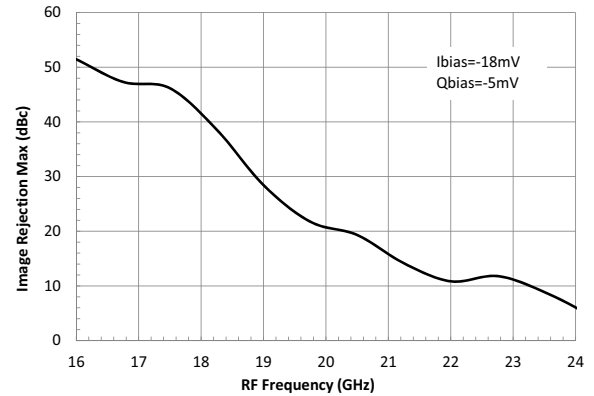
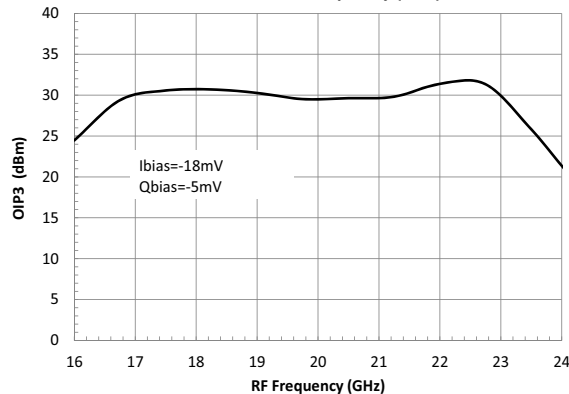


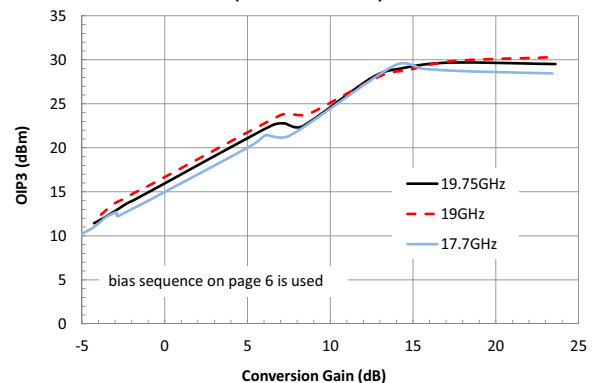
Image Rejection at Gmax versus RF Frequency (USB)



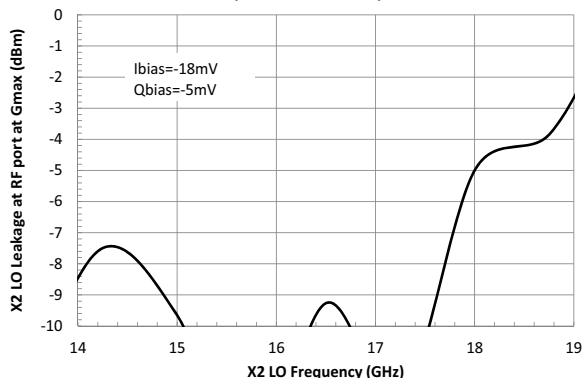
OIP3 versus RF Frequency (USB)



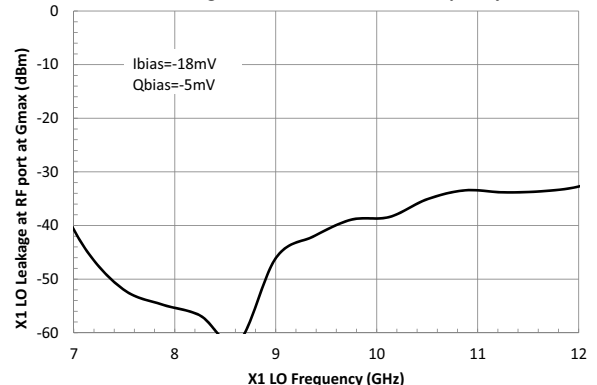
OIP3 versus Conversion Gain (USB 18GHz Band)



X2 LO Leakage at Gmax versus X2 LO Frequency (USB 18GHz Band)

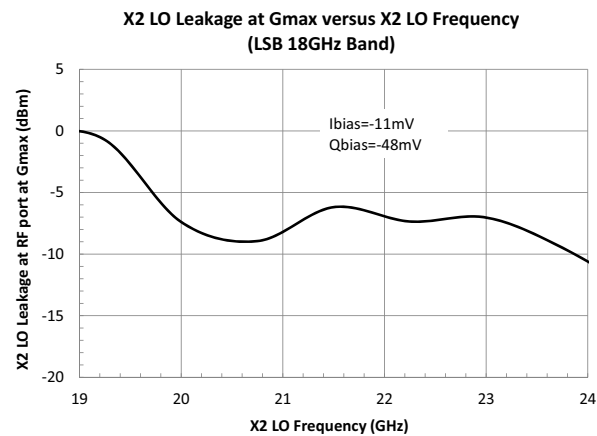
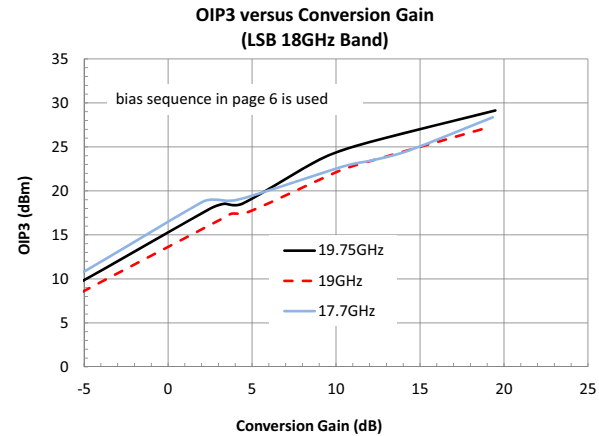
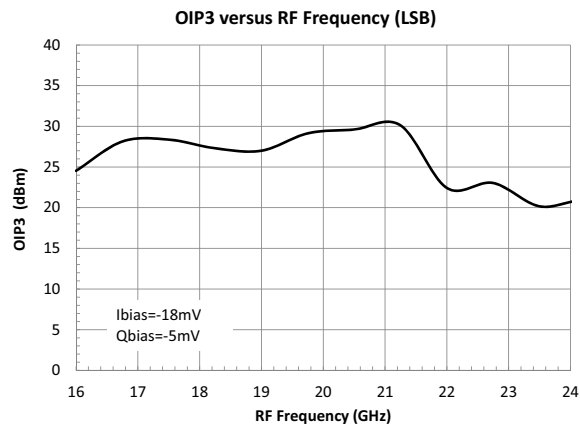
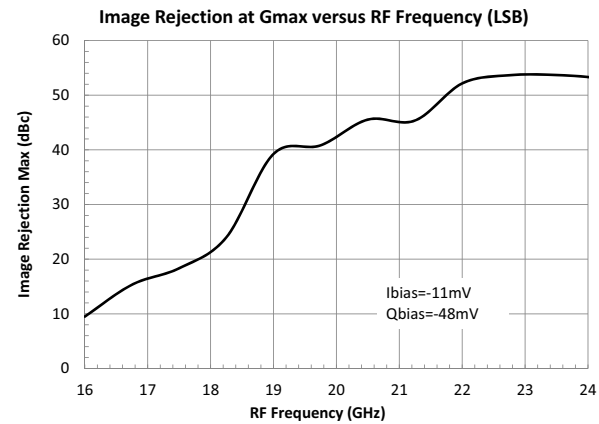
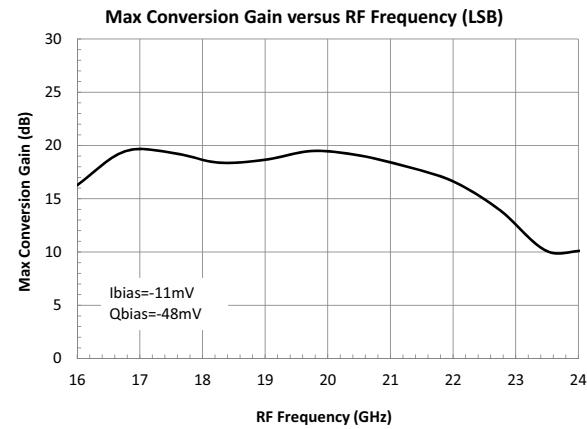


X1 LO Leakage at Gmax versus X1 LO Frequency



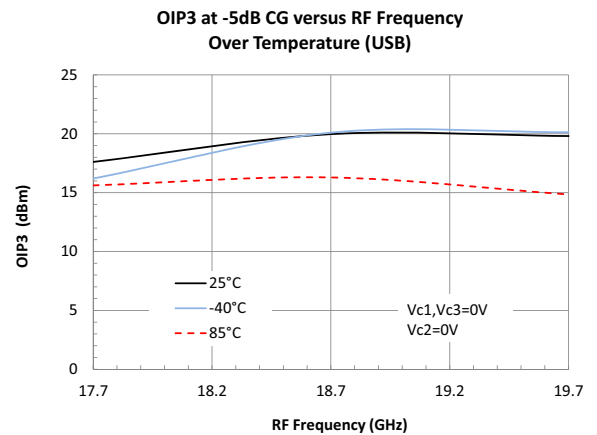
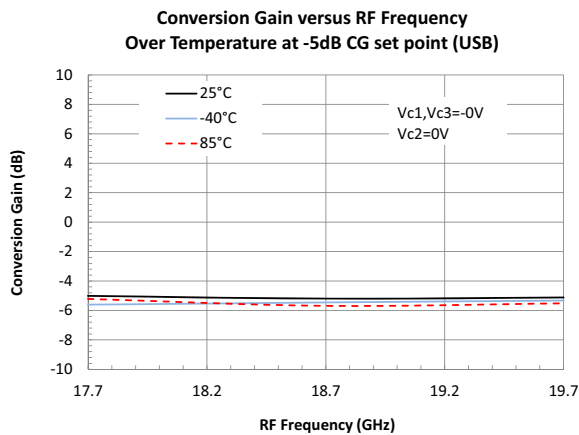
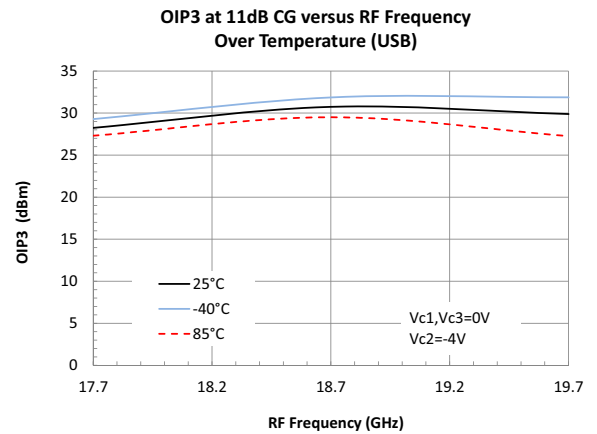
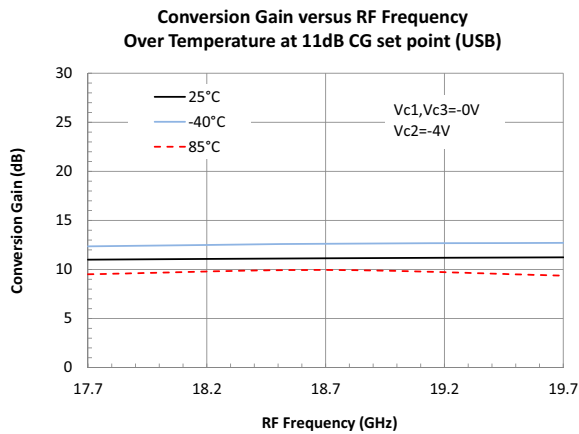
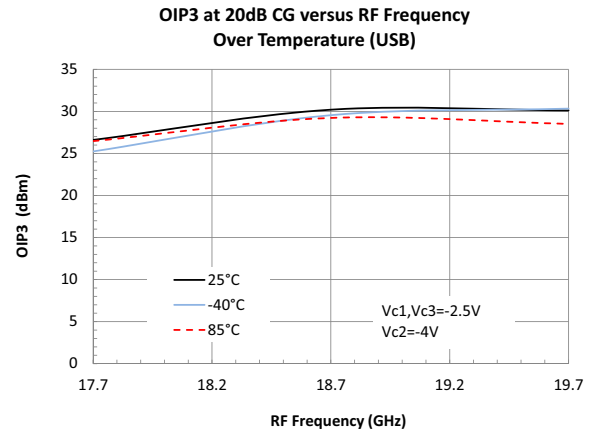
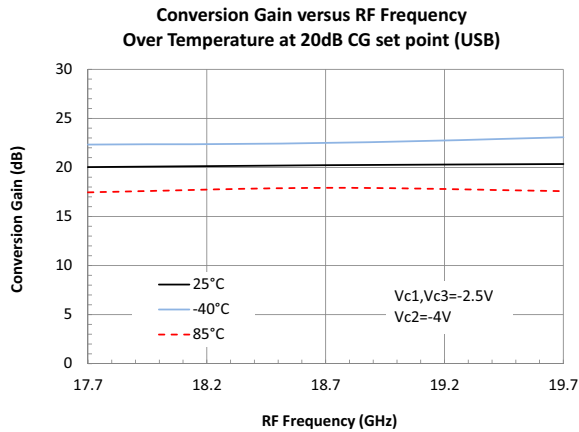
LO Frequency (13.5GHz to 21.5GHz)

LSB Conversion Gain, Image Rejection, OIP3, and LO Leakage



LO Frequency (18.5GHz to 26.5GHz)

Over Temperature Performance (USB)



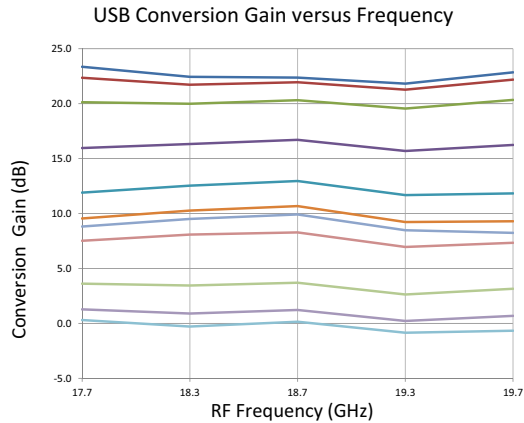
LO Frequency (15.2GHz to 17.2GHz)

Performance Using Single Control Line (without IQ bias)_1

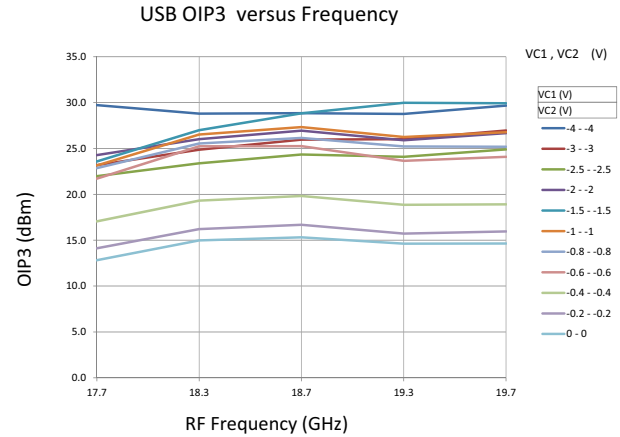
$V_{MPA} = 4.5V$, $V_{LPA12} = 3.5V$, $V_{LOA1} = V_{LOA2} = 4V$, $I_{total} = 450mA$, $V_{G1} = V_{G2} = -0.4V$, $V_{C3} = -4V$

V_{C1} and V_{C2} are connected together off chip and changes over (-4V to 0V)

Sum of CGain (dB)



Sum of OIP3(dBm)

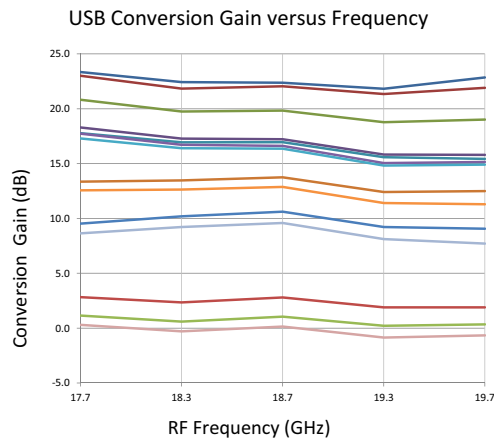


Performance Using Double Control Line (without IQ bias)_2

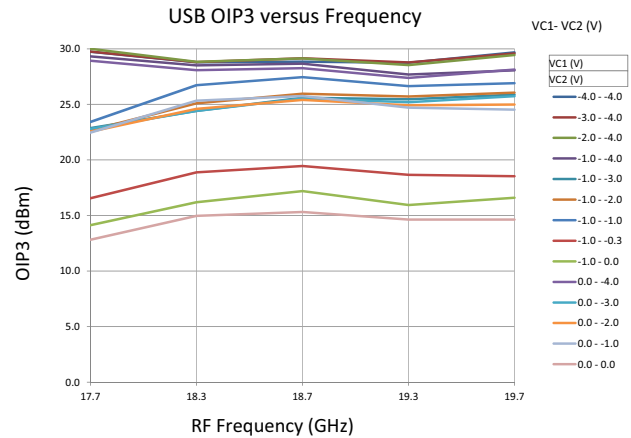
$V_{MPA} = 4.5V$, $V_{LPA12} = 3.5V$, $V_{LOA1} = V_{LOA2} = 4V$, $I_{total} = 450mA$, $V_{G1} = V_{G2} = -0.4V$, $V_{C3} = -4V$

V_{C1} and V_{C2} are separately controlled and changes over (-4V to 0V)

Sum of CGain (dB)



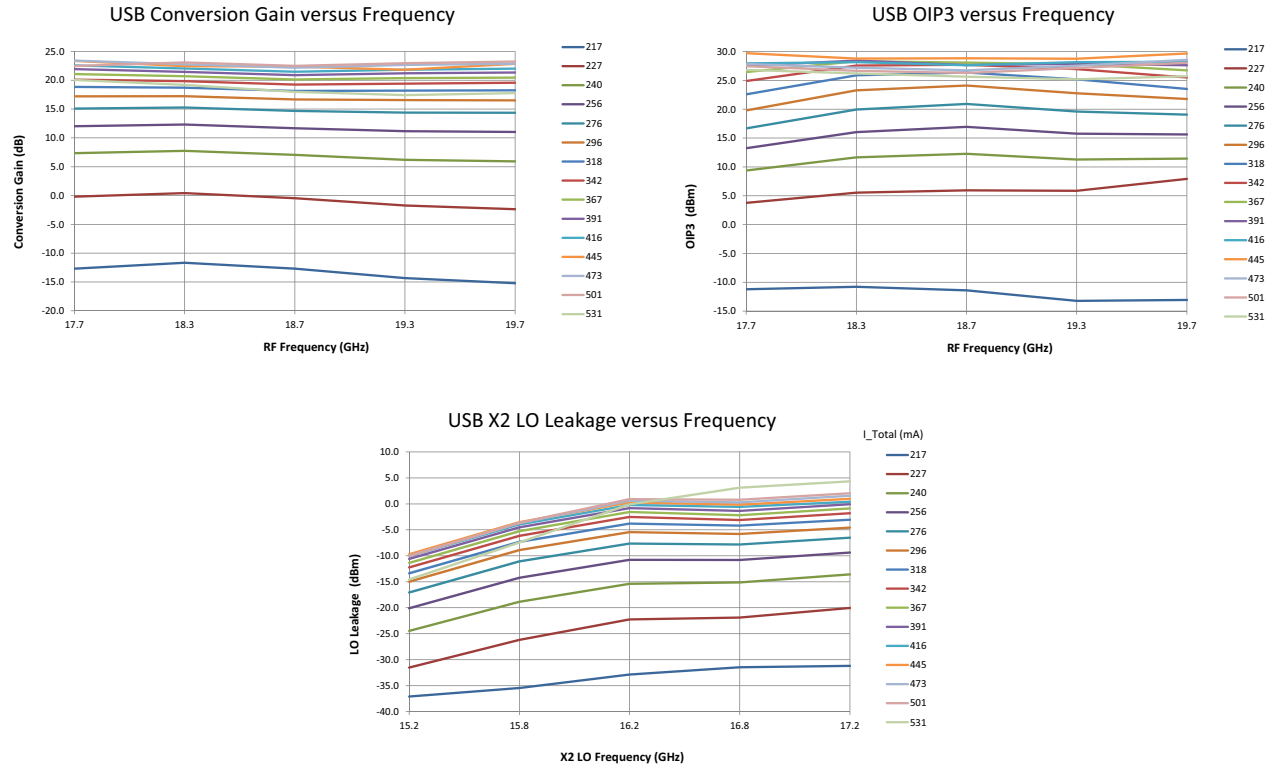
Sum of OIP3(dBm)



Performance Using Single Control on $V_{G1} = V_{G2}$ (without IQ bias)_3

$V_{MPA} = 4.5V$, $V_{LPA12} = 3.5V$, $V_{LOA1} = V_{LOA2} = 4V$, $V_{C1} = V_{C2} = V_{C3} = -4V$

V_{G1} and V_{G2} are connected together off chip and changes over (-0.3V to 1V)



Bias Sequence and Gain Control

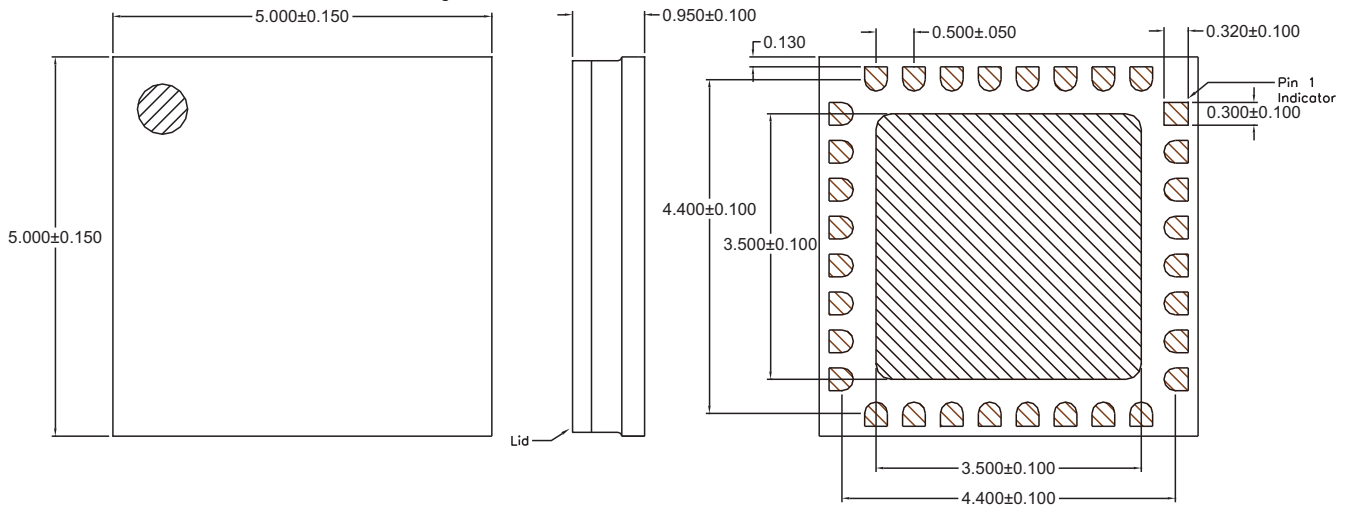
Optimum performance is achieved using sequential bias. At maximum gain (V_{C1} , V_{C3}), and V_{C2} are set at -4V and V_{G2} is set at -0.4V. (V_{C1} , V_{C3}), V_{C2} and V_{G2} are biased in sequence. The first dynamic range is achieved by setting (V_{C2} at -4V and V_{G2} at -0.4V) and varying (V_{C1} , V_{C3}) over the (-4 to -1V) range as shown in the table below. Similarly, the second dynamic range is achieved by setting (V_{C1} , V_{C3}) at -1V, V_{G2} at -0.4V and varying V_{C2} over the (-4 to -0.3V) range. Finally, the third dynamic range is achieved by setting (V_{C1} , V_{C3}) at -1V, V_{C2} at -0.3V and varying V_{G2} over the (-0.4 to -1V) range.

Test Conditions and Bias Sequence

Bias Sequence										
	G_{MAX}									G_{MIN}
(V_{C1} , V_{C3})	-4	-2	-1	-1	-1	-1	-1	-1	-1	-1
V_{C2}	-4	-4	-4	-2	-1	-0.3	-0.3	-0.3	-0.3	-0.3
V_{G2}	-0.4	-0.4	-0.4	-0.4	-0.4	-0.4	-0.6	-0.8	-0.9	-1

Package Outline Drawing

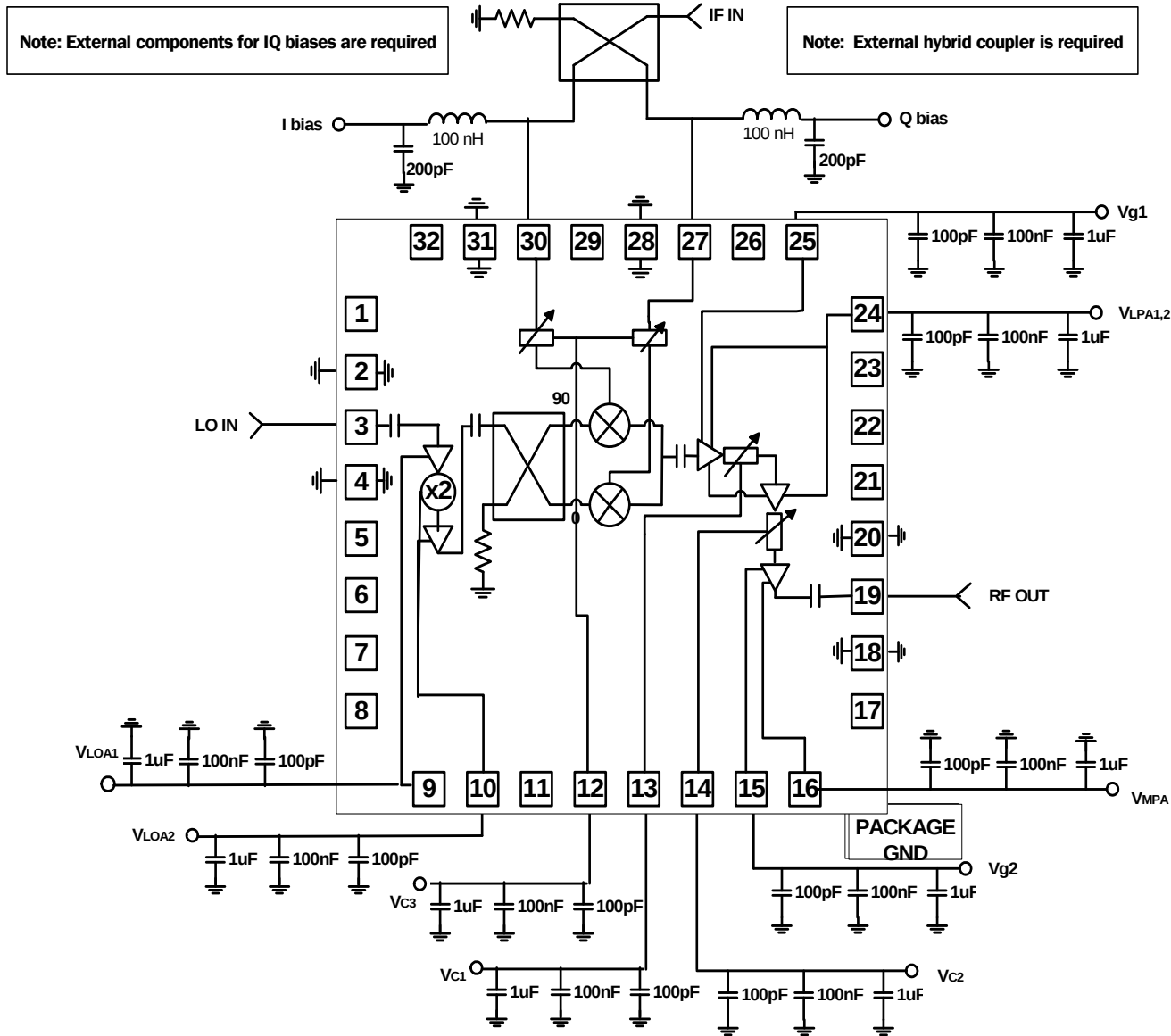
QFN, 32-Pin, 5mm x 5mm x 0.95mm



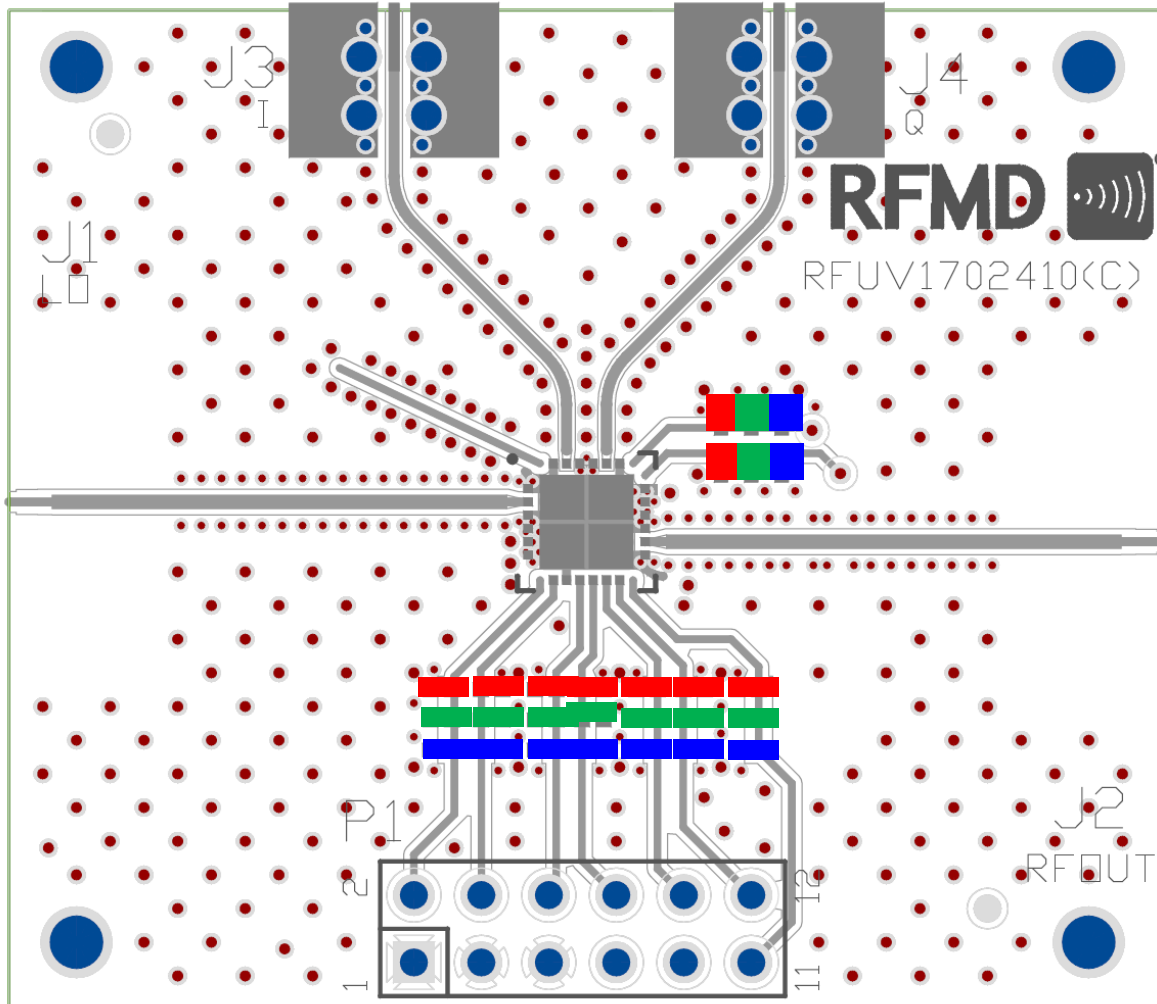
Pin Names and Description

Pin	Name	Description
1	N/C	Not Connected.
2	GND	Ground.
3	LO	Local Oscillator Input. AC Coupled and Matched to 50Ω.
4	GND	Ground.
5	N/C	Not Connected.
6	N/C	Not Connected.
7	N/C	Not Connected.
8	N/C	Not Connected.
9	VLOA1	LOA Stage1 Drain Bias.
10	VLOA2	LOA Stage2 Drain Bias.
11	N/C	Not Connected.
12	VC3	Control Line Number 3 (See Bias Sequence Description).
13	VC1	Control Line Number 1 (See Bias Sequence Description).
14	VC2	Control Line Number 2 (See Bias Sequence Description).
15	VG2	MPA Gate Bias.
16	VMPA	MPA Drain Bias.
17	N/C	Not Connected.
18	GND	Ground.
19	RFOUT	RF Output. AC Coupled and Matched to 50Ω.
20	GND	Ground.
21	N/C	Not Connected.
22	N/C	Not Connected.
23	N/C	Not Connected.
24	VLPA1, VLPA2	LPA Stage 1, 2 Drain Bias.
25	VG1	LPA Stage 1, 2 Gate Bias.
26	N/C	Not Connected.
27	Q	IF Q Input.
28	GND	Ground.
29	N/C	Not Connected.
30	I	IF I Input.
31	GND	Ground.
32	N/C	Not Connected.

Application Circuit Block Diagram



Evaluation Board Layout



100pF (0402)	VLOA1	VLOA2	VC3	VC1	VC2	VG2
100nF (0402)	GND	GND	GND	VG1	VLPA2	VMPA
1uF (0402)						

Test Condition

LO Power	0dBm
IF Power	-10dBm
V _{MPA}	4.5V, 120mA
V _{LPA1,2}	3.5V, 120mA
V _{LOA1} , V _{LOA2}	4V, 200mA
V _{C1} , V _{C3}	-4 to -1V (no current)
V _{C2}	-4 to -0.3V (no current)

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